

Description

The CSD16411Q3 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

V_{DS} = 30V I_D =60 A

 $R_{\text{DS(ON)}} < 8\,\text{m}\Omega @V_{\text{GS}} = 10V$

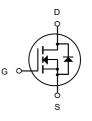
Application

Battery protection

Load switch Uninterruptible power supply







N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
CSD16411Q3	DFN3X3-8L	HXY MOSFET	5000

Absolute Maximum Ratings (TC=25°C unless otherwise specified)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	30	V
Vgs	Gate-Source Voltage	±20	V
I _D @Tc=25°C	Continuous Drain Current, V _{GS} @ 10V ¹	60	А
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	20	Α
Ідм	Pulsed Drain Current ²	140	А
EAS	Single Pulse Avalanche Energy ³	115.2	mJ
las	Avalanche Current	48	А
P _D @T _C =25°C	Total Power Dissipation ⁴	59	W
Тятд	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
R ₀ JA	Thermal Resistance Junction-ambient ¹	62	°C/W
Rejc	Thermal Resistance Junction-Case ¹	2.1	°C/W



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V_{GS} =0V , I _D =250uA	30			V
∆BV _{DSS} /∆Tj	BVDSS Temperature Coefficient	Reference to 25°C, I⊳=1mA		0.027		V/°C
		V _{GS} =10V , I _D =20A		6	8	
Rds(on)	Static Drain-Source On- Resistance ²	V _{GS} =4.5V , I _D =10A		7.5	10	mΩ
VGS(th)	Gate Threshold Voltage		1.2		2.5	V
riangle VGS(th)	V _{GS(th)} Temperature Coefficient	V _{GS} =V _{DS} , I _D =250uA		-5.8		mV/°C
lpss	Drain-Source Leakage Current	V _{DS} =24V , V _{GS} =0V , T _J =25°C			1	
IDSS	Drain-Source Leakage Current	V _{DS} =24V,V _{GS} =0V, T _J =55°C			5	uA
lgss	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =30A		43		S
Rg	Gate Resistance	V _{DS} =0V,V _{GS} =0V, f=1MHz		1.7		Ω
Qg	Total Gate Charge (4.5V)	V _{DS} =15V , V _{GS} =4.5V ,		20		nC
Qgs	Gate-Source Charge			7.6		
Qgd	Gate-Drain Charge	_I _D =15A		7.2		
Td(on)	Turn-On Delay Time			7.8		
Tr	Rise Time	-V _{DD} =15V , V _{GS} =10V ,		15		
Td(off)	Turn-Off Delay Time	-R _G =3.3Ω		37.3		ns
T _f	Fall Time	_I _D =15A		10.6		
Ciss	Input Capacitance			2295		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V ,		267		pF
Crss	Reverse Transfer Capacitance	_f=1MHz		210		۴.
ls	Continuous Source Current ^{1,6}	V _G =V _D =0V , Force			40	Α
lsм	Pulsed Source Current ^{2,6}	Current			140	А
Vsd	Diode Forward Voltage ²	V _{GS} =0V , I _S =1A , T _J =25°C			1	V

Electrical Characteristics (T_A=25°C unless otherwise noted)

Diode Characteristics

Note :

1. The data tested by surface mounted on a 1 inch $^2\,\mbox{FR-4}$ board with 2OZ copper.

2.The data tested by pulsed , pulse width \leq 300us , duty cycle $\leq 2\%$

3 .The EAS data shows Max. rating . The test condition is V_{DD} =25V, V_{GS} =10V,L=0.1mH,I_{AS}=34A

4.The power dissipation is limited by 150 $^\circ\text{C}$ junction temperature

5 .The data is theoretically the same as I_{D} and I_{DM} , in real applications , should be limited by total power dissipation.



Typical Characteristics

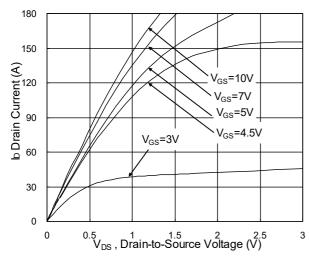


Fig.1 Typical Output Characteristics

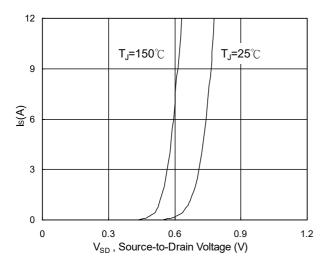


Fig.3 Forward Characteristics of Reverse

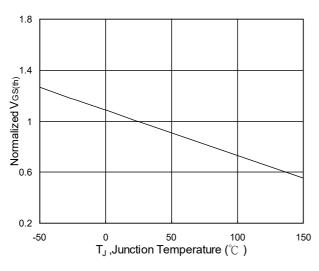


Fig.5 Normalized $V_{\text{GS}(\text{th})}$ vs. T_J

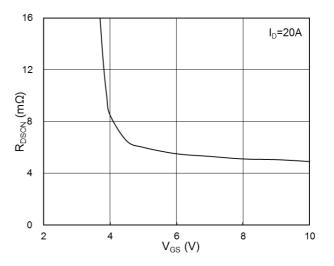


Fig.2 On-Resistance vs. G-S Voltage

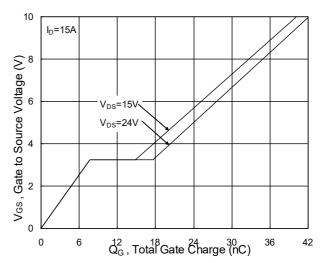


Fig.4 Gate-Charge Characteristics

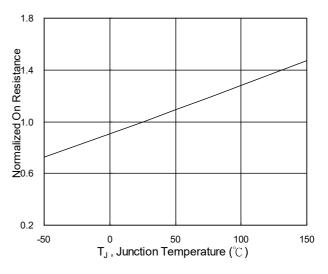
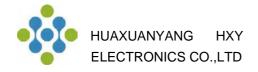


Fig.6 Normalized R_{DSON} vs. T_J



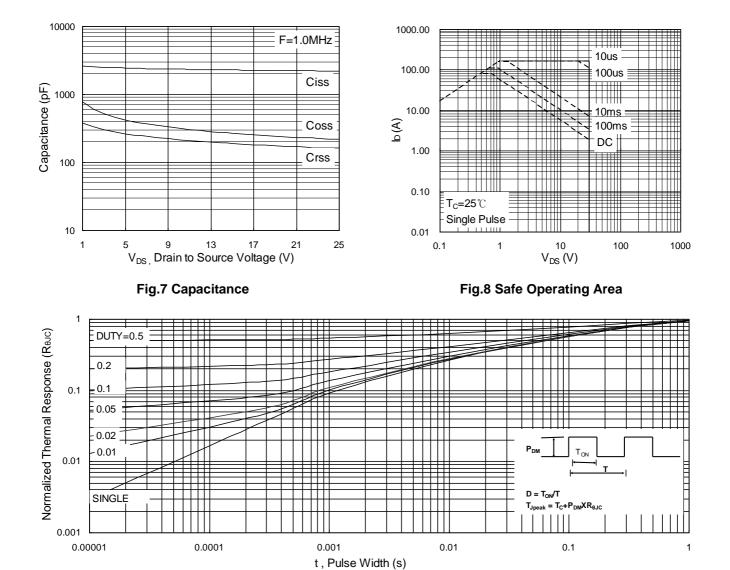


Fig.9 Normalized Maximum Transient Thermal Impedance

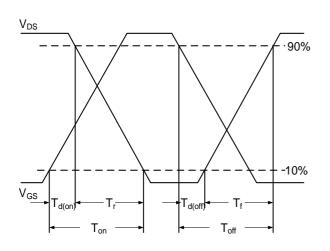


Fig.10 Switching Time Waveform

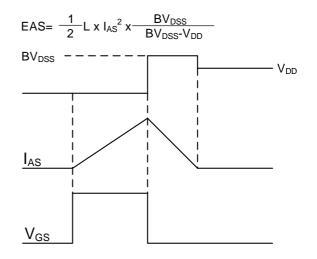
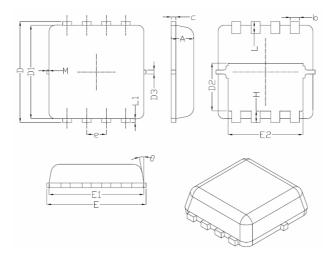


Fig.11 Unclamped Inductive Switching Waveform



DFN3X3-8L Package Information



Cumhal	Dimensions In Millimeters		
Symbol	Min.	Nom.	Max.
A	0.70	0.75	0.80
b	0.25	0.30	0.35
С	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.48	1.58	1.68
D3	-	0.13	-
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
Н	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	-	0.13	-
М	*	*	0.15
θ		10 [°]	12 [°]



Attention

Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.

• HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.

• Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

• HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could

give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

• In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

• No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.

Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production.
HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by HXY MOS manufacturer:

Other Similar products are found below :

IRFD120 JANTX2N5237 BUK455-60A/B MIC4420CM-TR VN1206L NDP4060 SI4482DY IPS70R2K0CEAKMA1 SQD23N06-31L-GE3 TK16J60W,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 DMN1053UCP4-7 SQJ469EP-T1-GE3 NTE2384 DMC2700UDMQ-7 DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 DMP22D4UFO-7B DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 STU5N65M6 DMN6022SSD-13 DMN13M9UCA6-7 DMTH10H4M6SPS-13 DMN2990UFB-7B IPB80P04P405ATMA2 2N7002W-G MCAC30N06Y-TP MCQ7328-TP BXP7N65D BXP4N65F AOL1454G WMJ80N60C4 BXP2N20L BXP2N65D BXT1150N10J BXT1700P06M TSM60NB380CP ROG RQ7L055BGTCR DMNH15H110SK3-13 SLF10N65ABV2 BSO203SP BSO211P IPA60R230P6 IPA60R460CE